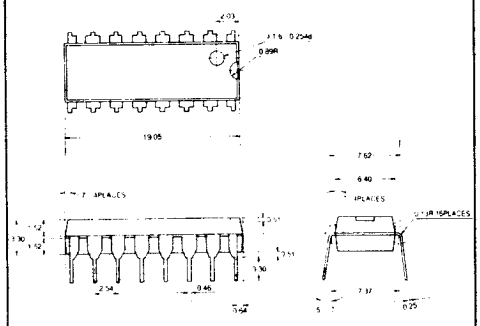
DBL 494

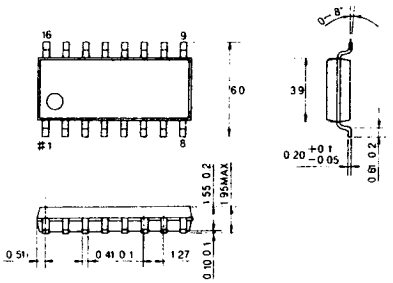
PULSE WIDTH MODULATION

The DBL494 is a monolithic integrated circuit which includes all the necessary building blocks for the design of pulse width modulated(PWM) switching power supplies, including push-pull, bridge and series configuration. The device can operate at switching frequencies between 1KHz and 300KHz and output voltages up to 40 V. The DBL494 is specified over an operating temperature range of 0°C to 70°C

16DIP Unit: mm



16SOP DBL 494-V



☐ FEATURES

- ○ Uncommitted output transistors capable of 200mA source or sink.
- ○ Internal protection from double pulsing of outputs with narrow pulse widths or with supply voltages belows specified limits.
- ○ Dead time control comparator
- ○ Output control selects single-ended or push-pull operation
- ○ Easily synchronized(slaved) to other circuits.

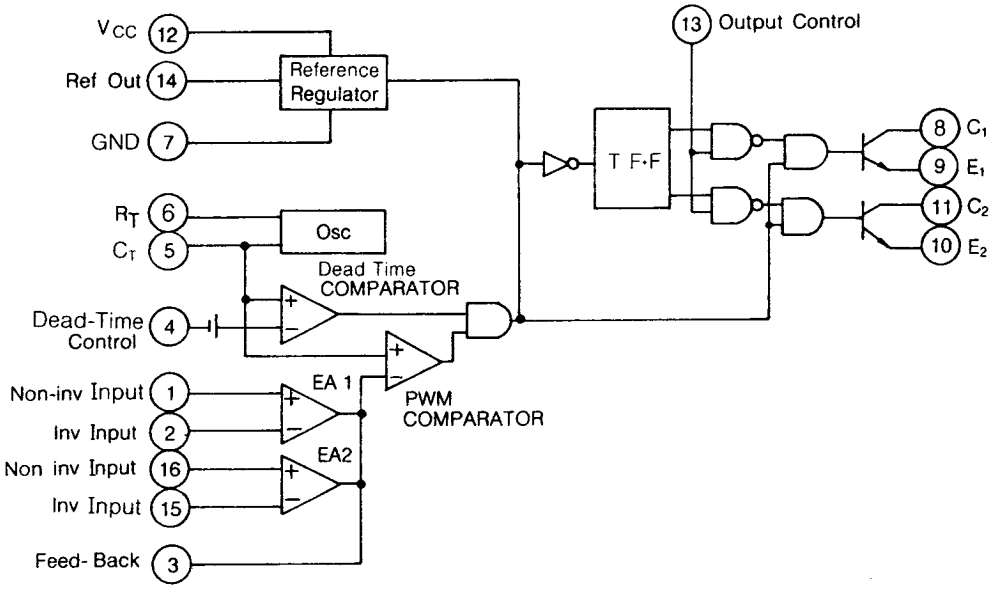
☐ MAXIMUM RATINGS

Characteristic	Symbol	Rating	Unit
Supply Voltage	V_{CC}	42	V
Voltage From Any Pin to Ground (except pin 8 and pin 11)	V_{IN}	V_{CC} +0.3	V
Output Collector Voltage	V_{C1}, V_{C2}	42	V
Peak Collector Current	I_{C1}, I_{C2}	250	mA
Power Dissipation	P_D	1500	mW
Operating Temperature	T_{opr}	0~+70	°C
Storage Temperature	T_{stg}	−65~+150	°C

☐ RECOMMENDED OPERATING CONDITION

Characteristic	Symbol	Min.	Max.	Unit
Supply Voltage	V_{CC}	7	40	V
Voltage on Any Pin Except Pin 8 and 11(Referenced to Ground)	V_{IN}	−0.3	V_{CC} +0.3	V
Output Voltage	V_{C1}, V_{C2}	−0.3	40	V
Output Collector Current	I_{C1}, I_{C2}	–	200	mA
Timing Capacitor	C_t	470	–	PF
		–	10	μF
Timing Resistor	R_t	1.8	500	KΩ
Oscillator Frequency	fosc	1	300	KHz

☐ BLOCK DIAGRAM



☐ ELECTRICAL CHARACTERISTICS

(Unless otherwise specified, Ta = 0~70°C, V_{CC} = 15V, f = 10kHz)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Reference Section						
Reference Voltage	V_{REF}	I_{REF} = 1.0mA	4.75	5	5.25	V
Line Regulation	V_{LINE}	7V < V_{CC} < 40V	—	2	25	mV
Load Regulation	V_{LOAD}	1mA < I_{REF} < 10mA	—	1	15	mV
Temperature Coefficient		0°C < Ta < 70°C	—	0.01	0.03	%/°C
Oscillator Section						
Oscillator Frequency	fosc	C_t = 0.01μF, R_t = 12KΩ	—	10	—	KHz
Oscillator Freguency Change Over Operating Temperature Range	△ fosc	C_t = 0.01μF, R_t = 12KΩ	—	—	2	%
Dead-Time Control Section						
Input Bias Current(Pin4)	I_{IB}(DT)	V_{CC} = 15V, 0V < V_4 < 5.25V	—	−2	−10	μA
Maximum Duty cycle, Each Output	DC(MAX)	V_{CC} = 15V, Pin 4 = 0V, Output Control Pin = V_{REF}	43	—	45	%
Input Threshold Voltage — Zero Duty	V_{TH}	—	—	3	3.3	V
Input Threshold Voltage — Max Duty	V_{TH}	—	0	—	—	V
Error Amplifier Section						
Input Offset Voltage	V_{IOS}	V_3 = 2.5V	—	2	10	mV
Input Offset Curren*	I_{IOS}	V_3 = 2.5V	—	25	250	nA
Input Bias Current	I_{IB}	V_3 = 2.5V	—	0.2	1	μA
Input Common Mode voltage Range	V_{ICR}	7V < V_{CC} < 40V	−0.3	—	V_{CC}	V
Large Signal Open Loop Voltage Range	G_{VO}	0.5V < V_3 < 3.5V	60	74	—	dB
Unity Gain Band width	fc	—	—	650	—	KHz
PWM Compacator Section(Pin3)						
Inhibit Threshold Voltage	V_{THI}	Zero Duty cycle	—	4	4.5	V
*Output Source Current	I_{O^+}	0.5V < V_3 < 3.5V	2	—	—	mA
*Output Sink Current	I_{O^-}	0.5V < V_3 < 3.5V	−0.2	−0.6	—	mA
Output Section						
Output Saturation Voltage — Common-Emitter	$V_{CE(SAT)}$	V_E = 15V I_C = 200mA	—	1.1	1.3	V
Output Saturation Voltage — Emitter-Follower	$V_{CE(SAT)}$	V_C = 15V, I_E = 200mA	—	1.5	2.5	V
Collector off-state Current	I_C(off)	V_{CC} = V_C = 40V, V_E = 0	—	2	100	μA
Emitter off-state Current	I_E(off)	V_{CC} = V_C = 40V, V_E = 0	—	—	-100	μA

* : These limits apply when the voltage measured at Pin 3 is with in the range specified.

☐ ELECTRICAL CHARACTERISTICS (Continued)

Characteristic		Symbol	Test Condition	Min.	Typ.	Max.	Unit
Out put Control(Pin 13)							
Output Control Voltage Required for single-Ended or Parallel Output Operation		V_{OCL}				0.4	V
Output Control Voltage Required for Push-pull operation		V_{OCH}		2.4			V
Total Device							
Standby power Supply Current		I_{CC}			6	10	mA
Output AC Characteristic							
Rise Time	Common Emitter	T_r			100	200	ns
	Emitter Follower				100	200	ns
Fall Time	Common Emitter	T_f			25	100	ns
	Emitter Follower				40	100	ns

☐ INFORMATION

The basic oscillator(switching)frequency is controlled by an external resistor (R_t) and capacitor(C_t). The relationship between the values of R_t C_t and frequency is shown in

The level of the sawtooth wave form is compared with an error voltage by the pulse width modulated comparator. The output of the PWM Comparator directs the pulse steering flip flop and the output control logic.

The error voltage is generated by the error amplifier. The error amplifier boosts the voltage difference between the output and the 5V internal reference. See Figure 7 for error amp sensing techniques. The second error amp is typically used to implement current limiting.

The output control logic (Pin 13) selects either push-pull or single-ended operation of the output transistors (see Figure 6).

The dead time control prevents on-state overlap of the output transistors as can be seen is Figure 5. The dead time is approximately 3 to 5% of the total period if the dead time control(pin 4) is grounded. This dead time can be increased by connecting the dead time control to a voltage up to 5 V.

The frequency response of the error amps (Figure 11) can be modified by using external resistors and capacitors. These components are typically connected between the compensation terminal (pin 3) and the inverting input of the error amps(pin 2 or pin 15).

The switching frequency of two or more DBL494 circuits can be synchronized. The timing capacitor, C_t is connected as shown in Figure 8. Charging current is provided by the master circuit. Discharging is through all the circuits slaved to the master. R_t is required only for the master circuit.

☐ TEST CICUIT

Fig. 1 Error Amplifier Test Circuit

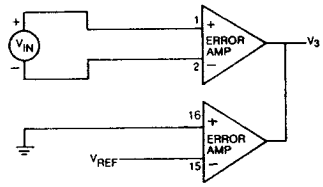


Fig. 2 Current Limit sense Amplifier Test Circuit

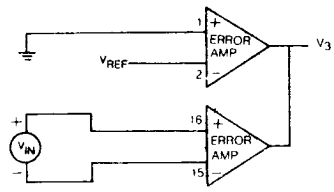


Fig. 3 Common-Emitter Configuration Test circuit and Waveform

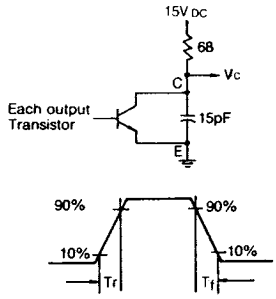


Fig. 5 Dead-Time and Feedback Control Test Circuit

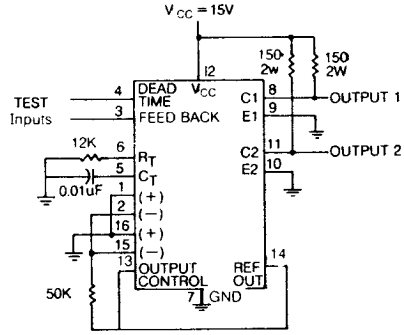
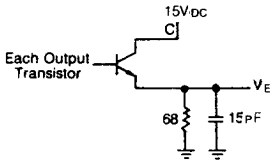
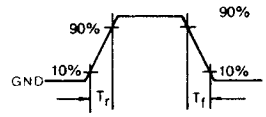
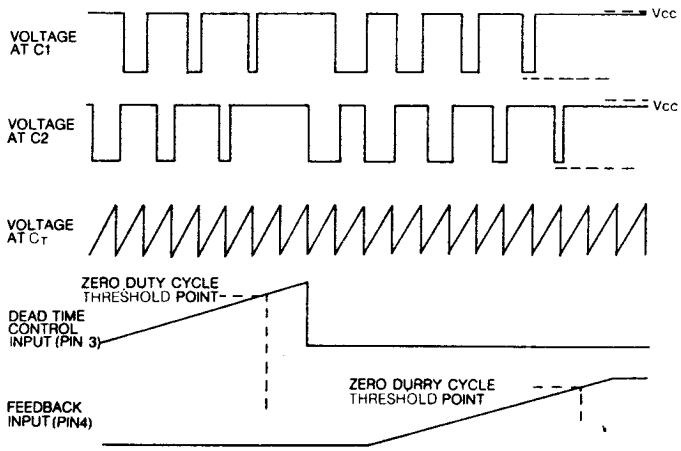


Fig. 4 Emitter-Follower Conflguration Test circuit and waveform Voltage waveforms





Voltage waveforms



☐ TEST CICUIT

Fig. 1 Error Amplifier Test Circuit

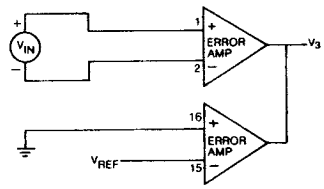


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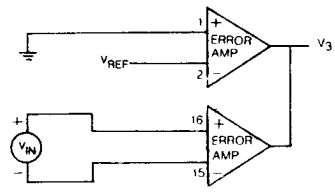


Fig. 3 Common-Emitter Configuration Test circuit and Waveform

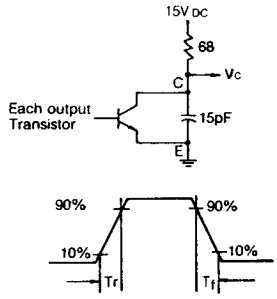


Fig. 5 Dead-Time and Feedback Control Test Circuit

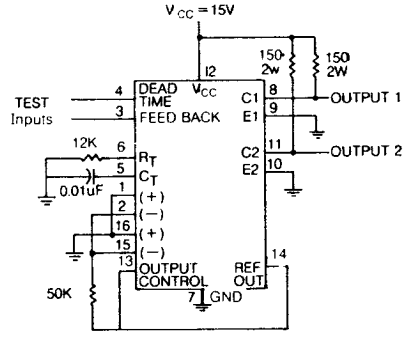
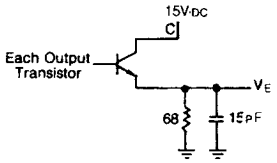
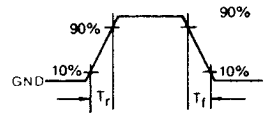


Fig. 4 Emitter-Follower Conflguration Test circuit and waveform Voltage waveforms





Voltage waveforms

